

APPLICATION DATA SHEET

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Title of Invention: METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE

Suggested Representative Figure: 1

I state that this resubmission of the application contains no new matter. If this resubmission is a redacted copy of an application submitted under CFR 1.217, the applicant hereby certifies that the redacted copy of the application eliminates only the part or description of the invention that is not contained in any application filed in a foreign country, directly or through a multilateral international agreement, that corresponds to the application filed in the Office and otherwise does not introduce any new matter. Additionally, if this submission is a redacted copy of an application submitted under 37 CFR 1.217, the applicant further certifies that the documents and certification required by 37 CFR 1.217(c) have been filed or will be filed within the deadline in 37 CFR 1.217(a).

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